NSN 5961-00-929-5014

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Inclosure Material:

Metal

Overall Length:

1.573 inches

Overall Height:

0.450 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

160.0 collector to base voltage/static/emitter open and 160.0 collector-to-emitter, with voltage between base and emitter and 140.0

collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

Between 4.00 amperes source cutoff current and 8.00 amperes source cutoff current

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

2 pin and 1 case

Specification Data:

80131-release5066 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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